VS-MBRS130LTRPbF

Vishay Semiconductors

RoHS

COMPLIANT

High Performance Schottky Rectifier, 1.0 A

### **FEATURES**

- · Small foot print, surface mountable
- · Very low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-MBRS130LTRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UN					
I <sub>F(AV)</sub>	Rectangular waveform	1.0	A				
V <sub>RRM</sub>		30	V				
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	230	A				
V <sub>F</sub>	1.0 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.30	V				
TJ	Range	-55 to +125	°C				

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-MBRS130LTRPbF	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	30	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	50	v			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at $T_L$ = 112 °C, rectangular waveform		1.0		
Maximum peak one cycle	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	230	А	
non-repetitive surge current		10 ms sine or 6 ms rect. pulse	$V_{\text{RRM}}$ applied	40		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 6 mH		3.0	mJ	
Repetitive avalanche current	I <sub>AR</sub>			1.0	А	



**PRODUCT SUMMARY** 

Package

I<sub>F(AV)</sub>

 $V_R$ 

V<sub>F</sub> at I<sub>F</sub>

I<sub>RM</sub> max.

T<sub>J</sub> max.

Diode variation

 $E_{AS}$ 



SMB 1.0 A

30 V

0.30 V

20 mA at 125 °C

125 °C

Single die

3.0 mJ



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
	V <sub>FM</sub> <sup>(1)</sup>	1 A	T <sub>J</sub> = 25 °C	0.420	V	
Maximum forward valtage drop		2 A		0.470		
Maximum forward voltage drop		1 A	- T <sub>J</sub> = 125 °C	0.300		
		2 A		0.370		
	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		1	mA	
Maximum reverse leakage current		T <sub>J</sub> = 100 °C	$V_R = Rated V_R$	10		
		T <sub>J</sub> = 125 °C		20		
Maximum junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		200	pF	
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		2.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	T <sub>J</sub> <sup>(1)</sup>		-55 to +125	°C	
Maximum storage temperature range	T <sub>Stg</sub>		-55 to +150	U	
Maximum thermal resistance, junction to lead	R <sub>thJL</sub> <sup>(2)</sup>	DC operation See fig. 4	25	°C/W	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	C/VV	
Approvimeto weight			0.10	g	
Approximate weight			0.003	oz.	
Marking device		Case style SMB (similar to DO-214AA)	13	L	

#### Notes

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB



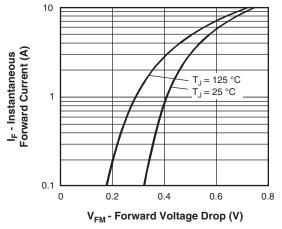


Fig. 1 - Maximum Forward Voltage Drop Characteristics

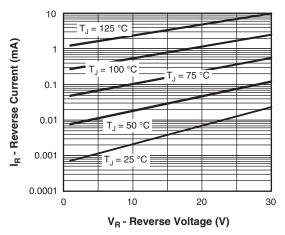


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

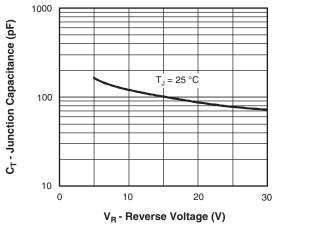


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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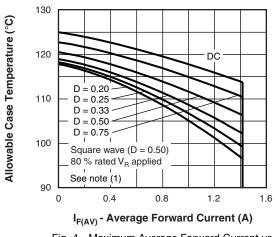


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

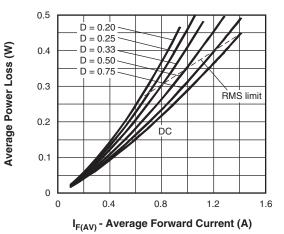


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

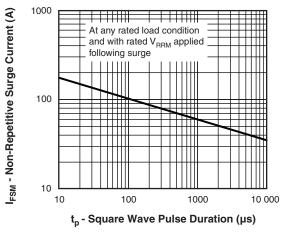


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

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#### **ORDERING INFORMATION TABLE**

Device code	VS-	MBR	S	1	30	L	TR	PbF
		2	3	4	5	6	7	8
	1 · 2 · 3 ·	Sch S =	nay Serr ottky M SMB rent rati	BR serie	es	oduct		
	5.	- Volt	tage rati	ng (30 =	= 30 V)			
	6	- L=	low forv	vard volt	age			
	7	- TR	= tape a	ind reel				
	8	- PbF	= lead	(Pb)-fre	е			

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION				
VS-MBRS130LTRPbF	5BT	3200	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95401				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			

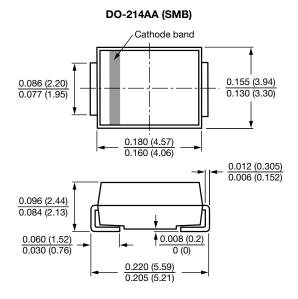


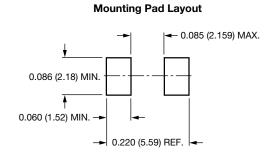
# **Outline Dimensions**

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**SMB** 

### **DIMENSIONS** in inches (millimeters)







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